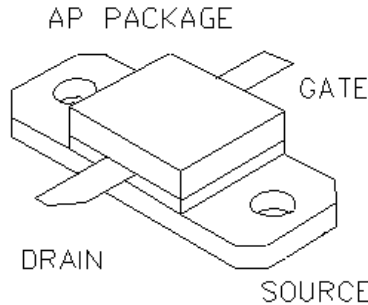




**General Description**

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"<sup>TM</sup> process features gold metal for greatly extended lifetime. Low output capacitance and high  $F_t$  enhance broadband performance



**PATENTED GOLD METALIZED SILICON GATE ENHANCEMENT MODE RF POWER VDMOS TRANSISTOR**

**2 Watts Single Ended**

**Package Style AP**

**HIGH EFFICIENCY, LINEAR, HIGH GAIN, LOW NOISE**

**ABSOLUTE MAXIMUM RATINGS (TC = 25 °C)**

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
20 Watts	10 °C/W	200 °C	-65 °C to 150 °C	0.8 A	50 V	50V	30V

**RF CHARACTERISTICS ( 2WATTS OUTPUT )**

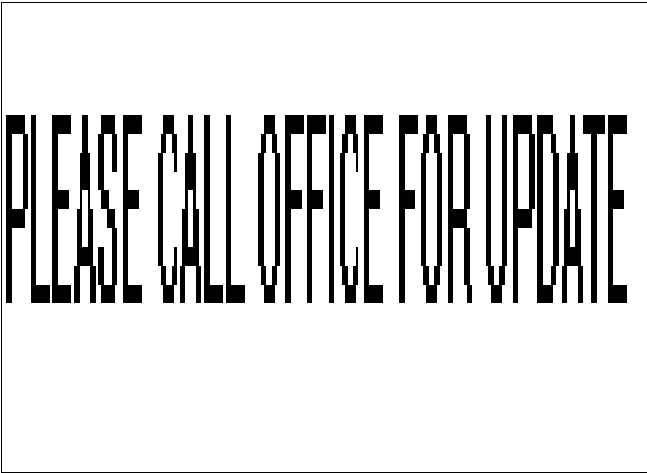
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	10			dB	Idq = 0.2 A, Vds = 12.5V, F = 850 MHz
$\eta$	Drain Efficiency		50		%	Idq = 0.2 A, Vds = 12.5V, F = 850 MHz
VSWR	Load Mismatch Tolerance			20:1	Relative	Idq = 0.2 A, Vds = 12.5V, F = 850 MHz

**ELECTRICAL CHARACTERISTICS (EACH SIDE)**

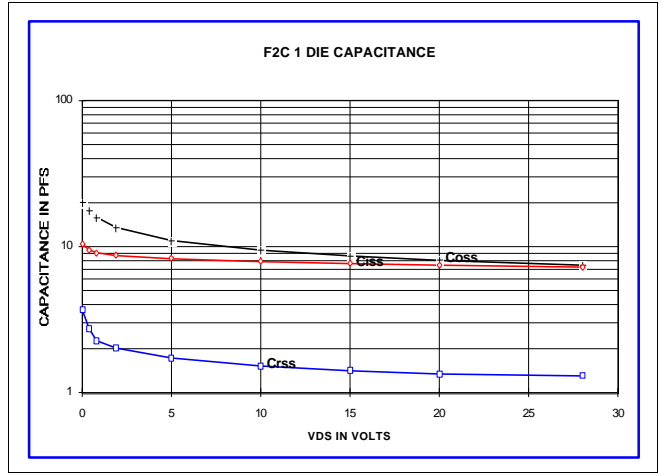
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	40			V	Ids = 0.01 A, Vgs = 0V
Idss	Zero Bias Drain Current			0.2	mA	Vds = 12.5 V, Vgs = 0V
Igss	Gate Leakage Current			1	uA	Vds = 0 V, Vgs = 30V
Vgs	Gate Bias for Drain Current	1		7	V	Ids = 0.02 A, Vgs = Vds
gM	Forward Transconductance		0.2		Mho	Vds = 10V, Vgs = 5V
Rdson	Saturation Resistance		2		Ohm	Vgs = 20V, Ids = 1.6A
Idsat	Saturation Current		2.3		Amp	Vgs = 20V, Vds = 10V
Ciss	Common Source Input Capacitance		7.5		pF	Vds = 12.5 V, Vgs = 0V, F = 1 MHz
Crss	Common Source Feedback Capacitance		1.2		pF	Vds = 12.5 V, Vgs = 0V, F = 1 MHz
Coss	Common Source Output Capacitance		8		pF	Vds = 12.5 V, Vgs = 0V, F = 1 MHz

# F2201

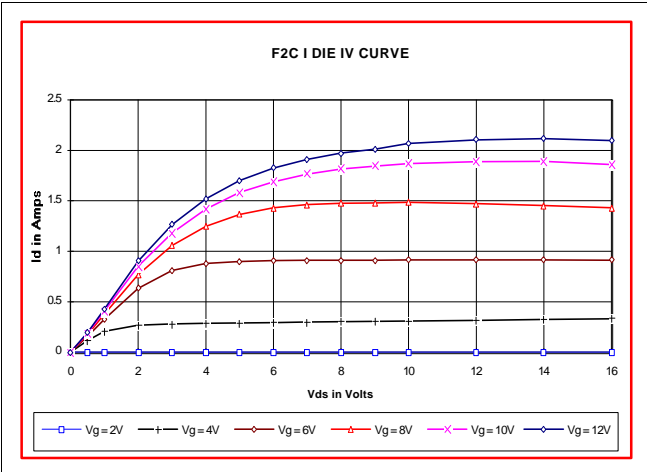
POUT VS PIN GRAPH



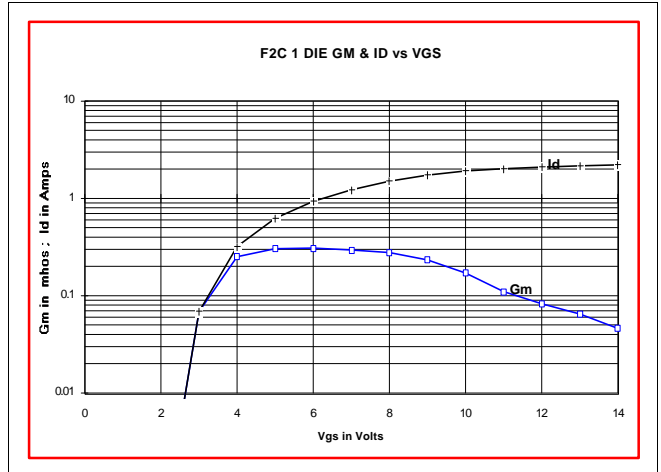
CAPACITANCE VS VOLTAGE



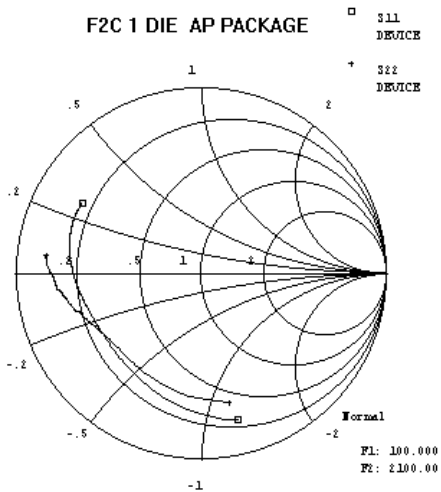
IV CURVE



ID AND GM VS VGS



S11 AND S22 SMITH CHART



PACKAGE DIMENSIONS IN INCHES

